PFM Step-up 4-cell Lithium Battery Charger IC CN3384

General Description:

CN3384 is a PFM mode step-up battery charge management IC with operating voltage range between 2.75V to 6.5V. It is specially designed for 4-cell lithium battery charge management with fewer external components. CN3384 adopts constant current and quasi-constant voltage(Quasi-CVTM) mode to charge battery.

On power up, CN3384 enters charging state, the external N-channel MOSFET is turned on, inductor current rises. When inductor current reaches upper threshold, the N-channel MOSFET is turned off, inductor is discharged, the energy stored in inductor is transferred to battery. When the inductor current is discharged to its lower threshold, the N-channel MOSFET is turned on again. When BAT pin voltage reaches 16.8V(Typ.) for the first time, CN3384 enters quasi-CV mode, in which the charge current is reduced. The charge process will not be terminated until BAT voltage reaches 16.8V for the second time. In termination mode, the N-channel MOSFET is turned off. When BAT voltage falls below recharge threshold, the CN3384 enters charge mode again. CN3384's switching frequency can be up to 1MHz, which makes a small-profile inductor usable. If battery voltage is lower than input voltage by a diode drop, CN3384 will increase the off time to 5us to reduce the charge current as a protection for battery with the joint action of external N-channel and P-channel MOSFET.

The other features include chip enable input, chip over temperature protection, current sense resistor short-circuit protection and status indication, etc. CN3384 is available in 8-pin SOP package.

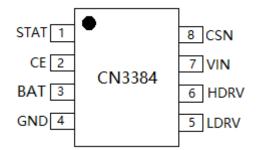
Applications:

- 3-cell Li+ Battery Charging Management
- Power Bank, POS, Electric Fan
- Audio System
- Standalone Charger

Features:

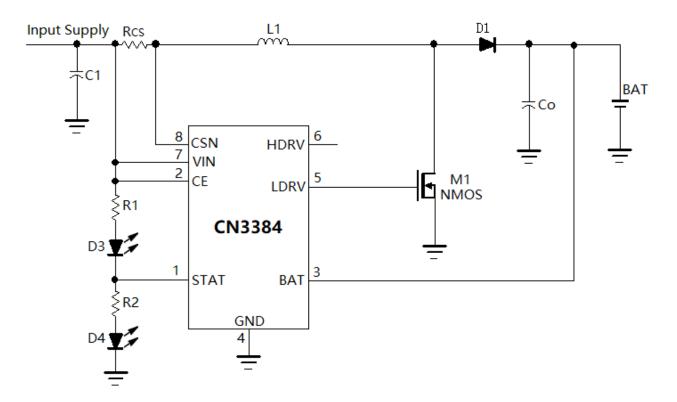
- Input Voltage Range: 2.75V to 6.5V
- Operating Current: 280uA@VIN=5V
- Can be Powered by Solar-panel
- Inductor Current Detection
- Switching Frequency up to 1MHz
- Quasi-CV mode to Compensate for the Voltage Loss on Battery Internal Resistance and Trace Resistance
- Short-circuit Protection for Current Sense Resistor
- Automatic Recharge
- Output Power up to 35W
- Protection for Low Battery Voltage and Short Battery
- Automatic Adaptability to Input Supply with Limited Driving Capability
- Chip Enable Input
- Chip Over Temperature Protection
- Battery Overvoltage Protection
- Status Indication
- Operating Temperature : -40° C to 85° C
- Available in SOP8 Package
- Lead-free, rohs-Compliant and Halogen Free

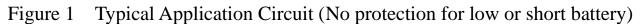
Pin Assignment

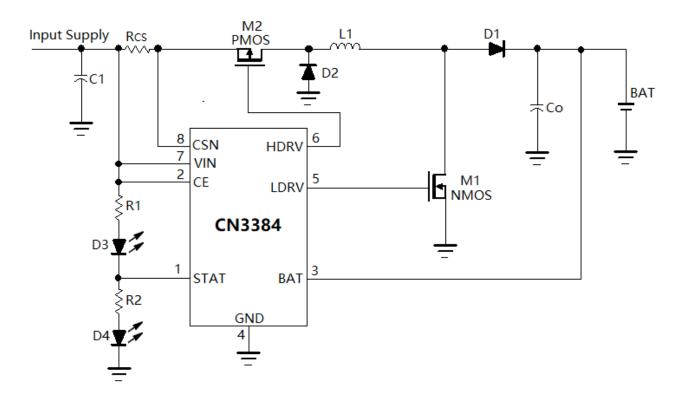


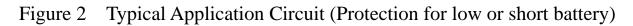
Note: Quasi-CV is the trade mark of Consonance Electronics

Typical Application Circuit:





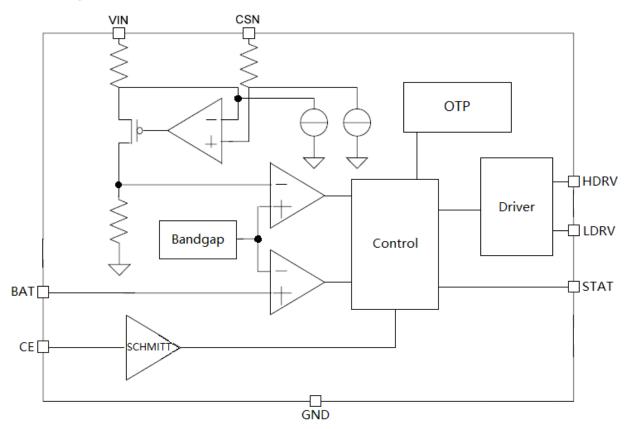




Ordering Information:

Part No.	Package	Shipping	Operating Temperature
CN3384	SOP-8	Tape and Reel, 4000/reel	-40° C to 85° C

Block Diagram:





Pin Description:

No.	Symbol	Description
		Status Indication Output. CMOS output. STAT pin's being high means
1	STAT	charger is in charging state; and charger is in termination state when STAT pin
		is low.
		Chip Enable Input. A high input will put the device in the normal operating
2	CE	mode. Pulling the CE pin to low level will put the CN3384 into disable mode.
		The CE pin can be driven by TTL or CMOS logic level.
3	BAT	Battery Positive Terminal. BAT pin should be tied to battery's positive
5	DAI	terminal to monitor battery voltage.
4	GND	GND. Ground, namely the negative terminal of input supply and battery.
5	LDRV	Gate Drive for external N-Channel MOSFET. Connect LDRV pin to the
5		gate of external N-Channel MOSFET.
		Gate Drive for external P-Channel MOSFET. Connect HDRV to the gate of
		external P-Channel MOSFET.
6	HDRV	If there is no need to consider the cases such as battery voltage being lower
		than input supply or short battery, then the P-Channel MOSFET is not needed,
		and leave HDRV pin floating.
7	VIN	Positive Terminal of Input Supply. CN3384's internal circuit is powered by
/	VIIN	this pin, VIN is also the positive terminal of inductor current sensing.
		Negative Terminal of Inductor Current Sensing. A current sense resistor
8	CSN	R_{CS} between VIN pin and CSN pin is used to sense inductor current, also the
0	CSN	input current. In constant current mode, (VIN-CSN) is regulated between
		85mV and 125mV.

ABSOLUTE MAXIMUM RATINGS

VIN, CSN and CE Voltage $-0.3V$ to $7.0V$
BAT Voltage
CSN and VIN Voltage $-0.3V$ to $0.3V$
STAT, LDRV and HDRV Voltage $-0.3V$ to VIN
CE and STAT Current15mA

Maximum Junction Temperature	150℃
Operating Temperature Range40°C	to 85°C
Storage Temperature−65°C	to 150°C
Lead Temperature(Soldering, 10s)	260°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERICS:

(VIN = 5V, TA = -40° C to +85°C, Typical values are at TA = +25°C, unless otherwise noted)

Parameters	Symbol	Tes	t Conditions	Min	Тур.	Max	Unit
Input Voltage Range	VIN			2.75		6.5	V
UVLO Threshold	V _{UVLO}					2.65	V
Operating Current	I _{VIN}	$V_{BAT} = 8.6V$	/, No Switching	200	280	360	uA
Turn-off Current	$\mathbf{I}_{\mathrm{off}}$	CE is Low			0	2	uA
Switching	\mathbf{f}_{SW}			200		1000	KHz
Inductor Current Sense C	Comparator						
Current Sense Threshold	V _{CSHI}	CC	$(VIN - V_{CSN})$ rises from 0V until	113	123	133	mV
High		Quasi-CV	$V_{LDRV} < 0.5V$	35	40	45	
Current Sense Threshold	Varia	CC	$(VIN - V_{CSN})$ falls	77	87	97	mV
Low	V _{CSLO}	Quasi-CV	$\frac{1}{V} from 0.2V till V_{LDRV} > (VCC - 0.5V)$	10	15	20	mV
Propagation Delay to Output High	t _{DPDH}	(VIN-V _{CS}	_N): 0.15V to 0.075V		72		ns
Propagation Delay to Output Low`	t _{DPDL}	$(VIN - V_{CSN}): 0.06V \text{ to } 0.135V$			66		ns
CSN Input Current	I _{CSN}					1	uA
BAT Pin							
Charge Termination Threshold	V _{term}	BAT voltag	e rises	16.632	16.8	16.968	V
Recharge Threshold	V _{rech}	BAT voltage falls		15.95	16.19	16.43	V
BAT Pin Current	I _{BAT}	V _{BAT} =16.8V		3	5	7.5	uA
Over Voltage Threshold	Vov	BAT voltage rises		1.044	1.0663	1.088	
Over Voltage Release Threshold	V _{OVRLS}	BAT voltage falls		1.003	1.0249	1.047	%V _{term}
LDRV Pin							
LDRV Source Current		V _{CSN} =VIN	$V_{DRV} = 0.5 \times VCC$		0.65		А
LDRV Sink Current		$V_{CSN} = VIN - 0.2V,$ $V_{LDRV} = 0.5 \times VCC$			0.65		А
LDRV Output High	V _{OH}	$I_{LDRV} = 5mA$		VCC-0	.3		V
LDRV Output Low	V _{OL}	$I_{LDRV} = -5$				0.3	V
HDRV Pin		1		1			I
HDRV Source Current			1-0.2V, BAT Short $10RV = 0.5 \times VCC$		0.8		А
HDRV Sink Current		V_{CSN} =VIN, BAT short to GND V_{HDRV} =0.5×VCC			0.8		А
HDRV Output High	V _{OH}	I _{HDRV} =5m	4	VCC-0	.3		V
HDRV Output Low	V _{OL}	$I_{HDRV} = -5$		†		0.3	V

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Parameters	Symbol	Test Conditions	Min	Тур.	Max	Unit	
CE Pin		•					
Input Low Voltage	V _{CEL}	CE voltage falls			0.7	V	
Input High Voltage	V _{CEH}	CE voltage rises	2.2			V	
Input Current	ICEL	CE=GND, VIN=6V	-1			uA	
	ICEH	CE=VIN=6V			1		
STAT Pin							
Sink Current	Isink	V _{STAT} =0.3V, Termination mode		10		mA	
Source Current	ISRC	V _{STAT} =4.7V, Charge mode	10			mA	
Over Temperature Protec	tion						
Over Temperature Threshold		Chip temperature rises		145		°C	
Over Temperature Release Threshold	T _{RLS}	Chip temperature falls	127			°C	
Short-circuit Protection f	or Current S	Sense Resistor R _{CS}					
Deglitch Time t _{SRT}		Short-circuit of current sense resistor R _{CS}	70		us		

Detailed Description:

The CN3384 is a step up charge management IC for 4-cell lithium batteries with input voltage range from 2.75V to 6.5V.

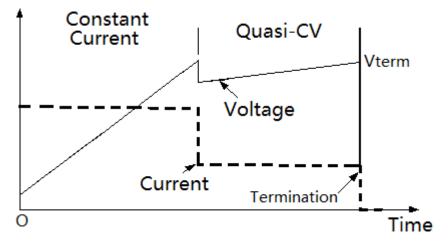
The CN3384 is composed of reference voltage, inductor current sensing circuit, battery voltage detection circuit, battery over voltage protection circuit, low battery protection, logic control block and MOSFET driver, etc. The CN3384 is ideally suitable for 4-cell lithium batteries charging application with fewer external components. CN3384 can also be powered by solar panel in addition to wall adaptors.

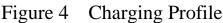
After power-on, CN3384 enters constant current charging mode, STAT pin outputs high to indicate that the charging is ongoing, the external N-channel MOSFET is turned on, the inductor current rises, and the energy stored in the output capacitor is transferred to battery. When the inductor current rises to the upper threshold, the N-channel MOSFET is turned off, the inductor current begins to fall, the energy stored in the inductor is transferred to the battery and the output capacitor. When the inductor current falls to the lower threshold, the external N-channel MOSFET is turned on again, and so forth. The battery voltage is sensed by the on-chip resistor divider. When the battery voltage reaches 16.8V(Typical) for the first time, CN3384 enters quasi-CV mode after deglitching. In quasi-CV mode, the charge current is reduced to 28% of that in constant current mode. When the battery voltage reaches 16.8V(Typical) for the second time, the charging is terminated, the external N-channel MOSFET is turned off, CN3384 enters termination mode, and STAT pin outputs low to indicate the termination mode. In termination mode, there is no current flowing to the battery, when the battery voltage falls to 16.19V(Typical), CN3384 enters constant current mode again.

The highest switching frequency of CN3384 can be up to 1MHz, which makes the low-profile inductor usable. CN3384 is a step-up charger IC, which means the battery voltage should be higher than the input voltage. In certain extreme cases, the battery voltage may be lower than the input voltage, or even the battery is shorted to GND, if these are the cases, the off-time of the external N-channel MOSFET will be lengthened, hence the charge current is reduced as a kind of protection to the battery.

The other functions include chip enable input (CE pin), chip over temperature protection, current sense resistor short-circuit protection and battery over voltage protection, etc.. 6

The charge profile is illustrated in Figure 4.





Application Information:

Input Voltage Range

The CN3384 functions well when the input voltage is between 2.75V to 6.5V. On-chip UVLO circuit will shut down the CN3384 if input voltage falls below UVLO threshold (2.65V Max.).

Chip Enable/Disable

There is a chip enable input CE pin. When the voltage at CE pin is above 2.2V, CN3384 functions normally; When the voltage at CE pin is below 0.7V, CN3384 is turned off. In turn-off state, the operating current is quite small (2uA Max.).

Do not apply a voltage between 0.7V and 2.2V on CE pin, otherwise CN3384 may be in uncertain state.

About Quasi-CV Mode

When the battery voltage is lower than 16.8V, CN3384 charges the battery with constant current. When battery voltage reaches 16.8V(Typical) for the first time, CN3384 enters quasi-CV mode, the charge current is reduced to 28% of that in constant current. When battery voltage reaches 16.8V(Typical) for the second time, CN3384 terminates the charging after deglitching. The quasi-CV mode can compensate for the voltage drop across the battery internal resistance to some extent, which is similar to constant voltage mode, this is why the quasi-CV mode is named.

Being powered by Solar Panel and Self-adaptive Function to Input Supply

CN3384 can adjust input current automatically to adapt the input supply's driving capability, which makes CN3384 ideal in applications of being powered by solar panel. This feature also makes it possible that the circuit design can be done based on the wall adaptor with strong driving capability for quick charge purpose, while the adaptor with weaker driving capability can also be used for charge purpose.

If input supply's driving capability is weak compared with the input current set by current sense resistor R_{CS} , CN3384 will regulate the input supply voltage by reducing input current. In this case the input supply voltage may fall as low as 2.7V, so the external MOSFETs should be selected in such a way that they can be fully turned on at about 2.7V.

To make sure CN3384 function correctly, the input supply like solar panel should be able to supply CN3384's operating current, which is about several milliamperes depending on the external N-channel MOSFET used.

Inductor Current (Input Current)

In the application circuit shown in Figure 1 and Figure 2, inductor current is sensed via the resistor R_{CS} connected between VIN and CSN pin.

When the external N-channel MOSFET is on, inductor current rises, when it reaches the upper threshold:

$$I_{Lhigh} = 0.123 V / R_{CS} \qquad (CC Mode)$$

 $I_{Lhigh} = 0.040 V / R_{CS} \qquad (Quasi-CV \ Mode)$

The N-channel MOSFET is turned off.

When the external N-channel MOSFET is off, inductor current falls, the energy is transferred to battery from inductor. When inductor current falls to:

 $I_{Llow} = 0.087V / R_{CS} \qquad (CC Mode)$ $I_{Llow} = 0.015V / R_{CS} \qquad (Quasi-CV)$

The external N-channel MOSFET is turned on again, a new cycle is started.

So the average inductor current is: $I_L = 0.105 V / R_{CS}$ (CC Mode)

 $I_L = 0.0275 V / R_{CS} \qquad (Quasi-CV)$

In the above 3 equations,

 I_{Lhigh} is upper threshold of inductor current in Ampere I_{Llow} is lower threshold of inductor current in Ampere R_{CS} is the inductor current sense resistor in ohm (Ω)

Calculate Switching Frequency and Inductor

In the application circuit shown in Figure 1 and Figure 2, the on-time of external N-channel MOSFET is:

The off-time of the N-channel MOSFET is:

$$t_{off} = \frac{0.04 \times L}{(V_{BAT} + V_D - VIN) \times R_{CS}} - - - - - - (2)$$

So the switching frequency is:

$$f_{sw} = \frac{1}{ton + toff} = \frac{1}{\underbrace{0.04 \times L}_{VIN \times Rcs} + \underbrace{0.04 \times L}_{(VBAT+VD-VIN) \times Rcs}}$$

CN3384 requires that the minimum switching frequency is no less than 200KHz. A frequency between 200KHz and 600KHz can achieve a good balance between efficiency and inductor size.

The switching frequency varies with input voltage and battery voltage, so when determining the switching frequency, the nominal battery voltage of 7.4V battery should be used.

Based on the requirements of input voltage range, charge current and switching frequency, the inductor value varies between 3.3uH and 15uH.

The duty cycle of CN3384 LDRV pin:

$$D = \frac{ton}{ton + toff} = \frac{V_{BAT} + V_D - VIN}{V_{BAT} + V_D}$$

In the above 2 equations:

L is the inductor value in Henry(H) VIN is the input voltage in Volt V_{BAT} is battery voltage in Volt V_D is the forward voltage drop of diode in Volt R_{CS} is the inductor current sense resistance in ohm(Ω)

Estimate Charge Current in Constant Current Mode

CN3384 controls charge current by monitoring inductor current, so the charge current in CC mode may vary with the input voltage and battery voltage.

Normally the following equation can be used to estimate the charge current:

$$I_{CH} = \frac{VIN X I_L X^{\gamma}}{V_{BAT}}$$

Where,

I_{CH} is charge current in Ampere

VIN is input voltage in Volts

 I_L is the average inductor current in Ampere, and decided by 0.106 / R_{CS}

 η is the conversion efficiency varying between 80% and 93%.

V_{BAT} is battery voltage in Volt

Charge Termination

When BAT pin voltage reaches 16.8V(Typical) in Quasi-CV state, the charging is terminated, the external N-channel MOSFET is turned off, no current flows to battery.

Recharge

In charge termination state, if voltage at BAT pin falls below 16.19V(Typical), CN3384 enters recharge state.

Selection of N-Channel MOSFETN

The CN3384's gate driver is capable of sourcing 0.65A and sinking 0.65A of current. MOSFET selection is based on the maximum battery voltage, inductor current and operating switching frequency. Choose an N-channel MOSFET that has a higher breakdown voltage than the maximum battery voltage, low Rds(ON), and low total gate charge(Qg) for better efficiency. MOSFET threshold voltage must be adequate if operated at the low end of the input-voltage operating range.

Selection of Free-Wheeling Diode

The forward voltage of the freewheeling diode (D1 in Fig.1 and Fig.2) should be as low as possible for better efficiency. A Schottky diode is a good choice as long as the breakdown voltage is high enough to withstand the maximum battery voltage. The current rating of the diode must be greater than the maximum charge current. D2 in Fig.2 is only used when the input voltage is higher than battery voltage, in this case the inductor current is lowered much, and the maximum voltage applied on the diode is input voltage, so most of the schottky diodes can be used for D2.

Input Capacitor

In most applications, a bypass capacitor at VIN is needed. An at least 4.7uF ceramic capacitor, placed in close proximity to VIN and GND pins, works well. In some applications depending on the power supply characteristics and cable length, it may be necessary to increase the capacitor's value. The capacitor's breakdown voltage should be higher than the maximum input voltage.

Generally a capacitor between 4.7uF and 47uF works well, ceramic capacitor of X5R or X7R is highly recommended.

Output Capacitor

A filter capacitor (Co in Figure 1 and Figure 2) is needed between battery positive terminal and ground, the capacitor also supply energy to battery when the N-channel MOSFET is in on state.

The output capacitance is determined by the requirement of output ripple voltage. The ripple voltage is decided by the following equation:

$$\Delta V_{BAT} = \frac{ICH \bullet toff}{Co} + \frac{0.04 \bullet r_{esr}}{Rcs}$$

Where, I_{CH} is the charge current flowing into battery

 $t_{\rm off}$ is the off time of N-channel MOSFET

Co is the output capacitance

resr is the equivalent series resistance of output capacitor

Rcs is the inductor current sense resistor shown in Figure 1 and Figure 2

So the ESR of output capacitor should be as small as possible, X5R or X7R ceramic capacitors are recommended.

Chip Over-Temperature Protection

If CN3384's silicon temperature rises above 145°C due to certain reasons, the over temperature protection mode is asserted, LDRV pin outputs low level which turns off the external N-channel MOSFET. In this case, CN3384 will not go back to normal operation until the silicon temperature falls below 127°C.

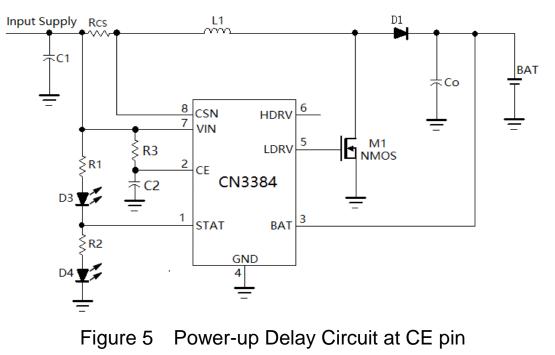
Short-circuit Protection for Current Sense Resistor (R_{CS})

The CN3384 provides short-circuit protection function for current sense resistor (R_{CS} in Figure 1 and Figure 2) by limiting the maximum on-time of LDRV pin. If the current sense resistor R_{CS} is in short condition, then the voltage drop across R_{CS} will not reach upper current sense threshold V_{CSHI} , LDRV pin will remain in high for more than 70us, then CN3384 enters R_{CS} short-circuit protection state, LDRV pin becomes low, charging is stopped. In this case, to make CN3384 back to normal operation, one of the following 2 measures can be adopted:

(1) Remove the input supply and re-apply to CN3384

(2) Cycle CE pin

On power up, if the voltage drop across R_{CS} reaches upper current sense threshold V_{CSHI} within 70us, then CN3384 can start functioning normally. If R_{CS} can't reach upper current sense threshold V_{CSHI} within 70us on power up due to the input power supply characteristics, or long cable, or large contact resistance, etc. the on-time of LDRV pin will be over 70us, then CN3384 can not start up normally and be latched in R_{CS} short-circuit protection state. To avoid this case happens, a delay circuit at CN3384's CE pin can be introduced as shown in Figure 5, in which R3 and C2 serves the purpose. Generally, R3 resistance can be around 100K Ω to 200K Ω , C2 capacitance can be 1uF.



Status Indication

CN3384's CMOS output STAT pin is for status indication. In charge state, STAT pin outputs high; In charge termination state, STAT pin outputs low.

STAT pin can drive LEDs directly or interface with MCU.

In the application circuit shown in Figure 1 and Figure 2, STAT pin is driving LEDs.

When STAT pin interfaces with MCU, if CN3384's operating voltage is higher than MCU's power supply, then the circuit shown in Figure 6 can be used:

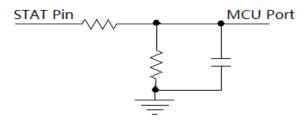


Figure 6 STAT Pin Interfaces with MCU

If 2 common-anode or common-cathode LEDs are to be driven, then the circuits in Figure 7 can be used.

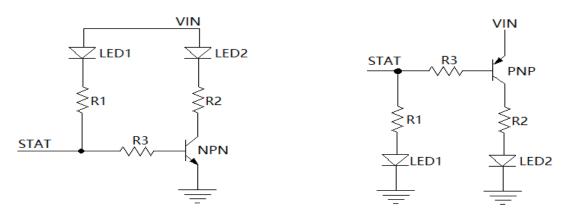


Figure 7 Drive 2 common-anode or common-cathode LEDs

When chip enable input is low, STAT pin outputs high, the LED for charge indication will be turned on. To turn off the LED when CE is low, the circuit in Figure 8 can be used.

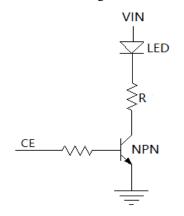


Figure 8 To Turn off LED when CE is low

Adjust Charge Termination Voltage upwards

The charge termination voltage can be adjusted upwards by placing a resistor between output and CN3384's BAT pin as shown in Figure 9.

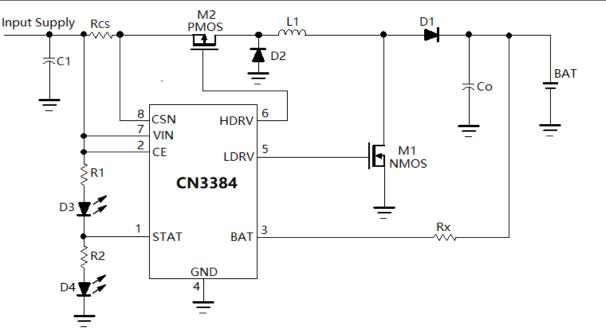


Figure 9 Adjust Charge Termination Voltage upwards

In Figure 9, the resistor Rx is used to adjust the charge termination voltage upwards. Because the resistance characteristics of Rx is different with that of on-chip resistor, it is better that the adjusted amplitude of charge termination voltage is no more than 0.4V.

The adjusted upward voltage amplitude is decided by the following equation:

 $Vx=4.87 \times 10^{-6} \times Rx$ (V)

Where, Rx is in ohm.

So the actual charge termination voltage is decided by:

Vterm=16.8+Vx (V)

Low Battery or Shorted Battery Protection

In normal operation, the battery voltage is higher than the input voltage. But in some cases, the battery voltage may be lower than input voltage, or even the battery is shorted to Ground. In these cases, the application circuit shown in Figure 2 should be adopt, otherwise the uncontrolled current may be flowing from input supply to the battery through the inductor and diode, which may be harmful to battery.

Design Procedures

The following design procedures can be followed to design the parameters of CN3384 application circuit:

- (1) To determine the charge current based on the battery capacity and the requirement of charge time.
- (2) To estimate the input current based on the input voltage range and charge current. The input current is also the inductor current.
- (3) To decide the input capacitor based on the input supply's characteristics, input supply's cable length and input current.
- (4) To select diode, N-channel MOSFET and P-channel MOSFET based on input voltage, inductor current and the battery's highest voltage.
- (5) To calculate the current sense resistor R_{CS} based on the average inductor current
- (6) To determine the inductor value according to the switching frequency. The switching frequency can be from 200KHz to 1MHz. Generally speaking, a switching frequency between 500KHz and 800KHz can achieve a good balance between efficiency and inductor's profile.
- (7) To select the output capacitor based on the switching frequency and charge current.

Design Example

The circuit parameters for Figure 1 and Figure 2 are shown in the following table for some typical scenarios. The circuit parameters are designed based on typical conditions without considering the specific application conditions and the environmental factors. The circuit parameters shown in the table are for reference only. (VIN=5V, Vterm=16.8V, I_{CH} is charge current, unless otherwise specified)

	I _{CH} =0.5A	I _{CH} =1A	I _{CH} =2A	I _{CH} =3A	
Inductor Current	1.8A	3.6A	7.2A	10.8A	
Innut Con C1	22mE 1206	22uF,1206	22uF,1206	22uF,1206	
Input Cap C1	22uF,1206	2X in parallel	3X in parallel	4X in parallel	
Diode D1	SS24 or SS34	SS24 or SS34	SS34	SS54 or 1N5824	
Diode D2	SS24 or SS34	SS24 or SS34 SS24 or SS34		SS34	
NMOS M1	SI2300,SI2302	1011(9	AO4468,	AO4410,	
	512500,512502	AO4468	AO4410	NCE3018S	
PMOS M2	SI2301,SI2305	AO4435	AO4435	AO4407A	
Current Sense	$80 {\rm m}\Omega$, 0.15W	40m Ω ,0.25W	20m Ω ,0.5W	$15m \cap 1W$	
Resistor R _{CS}	80111 S2 , 0.15 W	40III \$2,0.23 W	2011 ^{s2} ,0.5 W	15m Ω ,1W	
Inductor L1	6.8uH, I _{SAT} >2A	4.7uH,I _{SAT} >4A	3.3uH,I _{SAT} >8A	2.2uH,I _{SAT} >12A	
Switching	780KHz	560KHz	400KHz	400KHz	
Frequency	/ 00KTIZ	JUUNIIZ	400 N ΠZ		
Output Cap Co	10uF,0805	22uF,1206	22uF,1206	22uF,1206	
Output Cap Co	1001,0005	2201,1200	2X in parallel	3X in parallel	

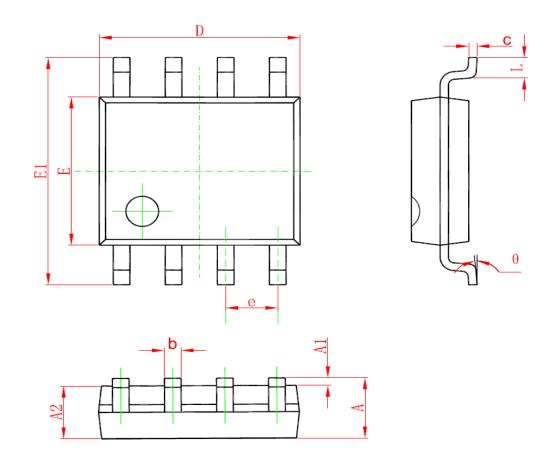
PCB Considerations

A good PCB design is very important to efficiency and performance. When laying out the printed circuit board, the following considerations should be taken to ensure proper operation of the IC.

- If possible, use multi-layer PCB for better performance.
- The ground connections of output capacitor, N-channel MOSFET, and catch diode (D2 in Figure 2) need to feed into same copper that connects to the input capacitor ground before tying back into system ground. This copper should be as wide as possible, and back to system ground separately.
- To minimize radiation, the 2 diodes, MOSFETs, inductor and the input bypass capacitor traces should be kept as short as possible. The connection between the diode and the MOSFETs should also be kept as short as possible.
- Place the inductor current sense resistor R_{CS} right next to the input capacitor and inductor but oriented such that the IC's CSN and VIN traces going to R_{CS} are not long. The 2 traces need to be routed together as a single pair on the same layer at any given time with smallest trace spacing possible.

Package Information

SOP8 PACKAGE OUTLINE DIMENSIONS



Court of	Dimensions Ir	n Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	1.350	1. 750	0.053	0.069	
A1	0. 100	0. 250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0. 330	<mark>0. 510</mark>	0.013	0.020	
С	0.170	0. 250	0.006	0.010	
D	4. 700	5.100	0. 185	0.200	
E	3.800	4.000	0.150	0. 157	
E1	5.800	6.200	0. 228	0. 244	
е	1. 270	(BSC)	0. 050	(BSC)	
L	0. 400	1.270	0.016	0.050	
θ	0°	8°	0°	8°	

Important Notice

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